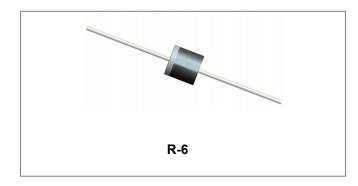






# 10A05G THRU 10A10G Glass Passivated Rectifiers



#### **Features**

- Low forward voltage drop
- · High current capability
- High reliability
- · High surge current capability
- Plastic material-UL flammability 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



#### **Mechanical Data**

- Case: R-6 molded plastic
- Terminals: Plated axial leads, solderable per MIL-STD-202, Method 208
- Polarity: Color band denotes cathode end
- Mounting Position: AnyWeight: 2.1 grams

#### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Type Number	Symbol	10A05G	10A1G	10A2G	10A4G	10A6G	10A8G	10A10G	Units
Maximum repetitive peak reverse voltage Maximum DC blocking voltage	$V_{RRM} \ V_{DC}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum average forward rectified current 0.375"(9.5mm) lead length at $@T_L = 100$ °C	I <sub>(AV)</sub>	10			А				
Non-Repetitive Peak Forward Surge Current 3.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		250				А			
I <sup>2</sup> t Rating for Fusing (t < 8.3ms)	l <sup>2</sup> t				259				A <sup>2</sup> s
Maximum instantaneous forward voltage at 10.0A	V <sub>F</sub>				1.1				V
Maximum DC reverse current @T <sub>A</sub> = 25°C At Rated DC Blocking Voltage @T <sub>A</sub> = 125°C	I <sub>R</sub>	5 100			μA				
Typical Junction Capacitance (Note 1)	CJ	150					pF		
Typical Thermal Resistance (Note 2)	R <sub>θJA</sub>	6					°C/W		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150					°C		

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

- 2. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length, P.C.B. mounted.
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#### **Ratings and Characteristics Curves**

FIG. 1 - FORWARD CURRENT DERATING CURVE

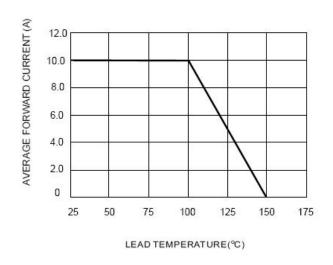
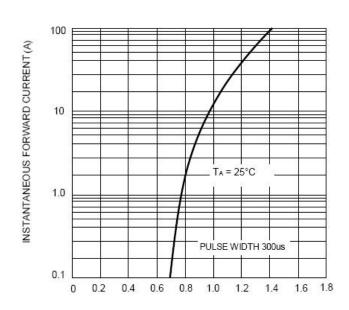


FIG.2-TYPICAL FORWARD CHARACTERISTICS



#### INSTANTANEOUS FORWARD VOLTAGE (V)

FIG. 3 - MAXIMUM NON-REPETITIVE SURGE CURRENT

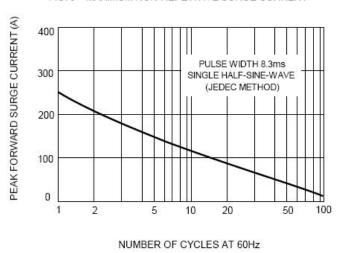
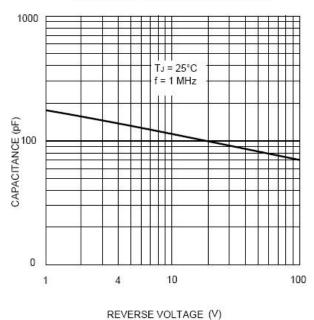


FIG.4 - TYPICAL JUNCTION CAPACITANCE



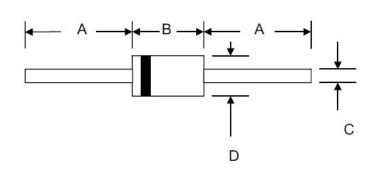
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## **Mechanical Dimensions R-6**



OVMPOL	Millim	neters	Inches			
SYMBOL	Min.	Max.	Min.	Max.		
А	25.4	-	1.000	-		
В	8.60	9.10	0.340	0.360		
С	1.2	1.3	0.048	0.052		
D	8.60	9.10	0.340	0.360		

## **Ordering Information**

Device	Package	Shipping
10A05G-10A10G	R-6(Pb-Free)	500pcs / tape
10A05GTA-10A10GTA	R-6(Pb-Free)	500pcs / tape
10A05GTR-10A10GTR	R-6(Pb-Free)	500pcs / reel

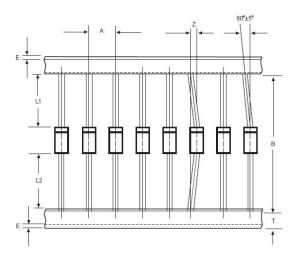
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



10A05G = Type Number

## **Carrier Tape Specification R-6**



SYMBOL	Millimeters			
	Min.	Max.		
А	9.50	10.50		
В	50.9	53.9		
Z	-	1.20		
Т	5.60	6.40		
E	-	0.80		
IL1-L2I	-	1.0		

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